

PDTD123ES,126 Information

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For Reference Only

Part Number PDTD123ES,126

Manufacturer NXP

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN 500MW TO92-3

Package TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









PDTD123ES,126 Specifications

Manufacturer Part Number	PDTD123ES,126
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	500mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	2.2k
DC Current Gain (hFE) (Min) @ Ic, Vce	40 @ 50mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 2.5mA, 50mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	-
Power - Max	500mW
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Supplier Device Package	TO-92-3
	Report errors?

PDTD123ES,126 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

PDTD123ES,126 Payment Methods









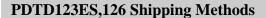
























If you have any question about PDTD123ES,126, please do not hesitate to contact us!

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